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control system.

[0001] The invention concerns a receiver arrangement for use in a remote-control system, and in particular, but not exclusively, a receiver arrangement for use in an infrared pulse position modulation (PPM) remote-

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[0002] Infrared remote-control systems are known in which an infrared diode is used in conjunction with appropriate circuitry in a receiver to pick up and demodulate data pulses transmitted from an infrared transmit-

ting diode situated at a point remote from the receiver. [0003] EP 0 564 349 discloses a remote-control receiver for a vehicle comprising an opto-electrical transducer connected to an amplifier. An integrator is connected to the. amplifier output and provides a signal which is subtracted from the transducer signal so as to eliminate low frequency parasitic signals from the transducer signal.

[0004] Another known form of a receiver front-end stage is shown in Figure 1. As seen from Figure 1, the stage centres around a bipolar transistor 12 arranged to receive the current output from an infrared diode 19. A resistor 13 is connected between the base and collector of the transistor 12, a capacitor 14 is connected between the base and a first reference potential 15, and a resistor 16 is connected between the same reference potential and the emitter of the transistor 12. A current source 17 is connected between a second reference potential 18 and the collector of the transistor 12, and the infrared diode 19 is connected in parallel with the current source 17. A diode 20 may also be interposed between the current source 17 and the collector of the transistor 12, for reasons which will be explained below.

[0005] The operation of the receiver stage, which functions as a form of current-to-voltage I=In flows into a node 21 of the receiver stage, when I_D is a quiescent current generated by the current source 17. This current is known as the "dark current" and sets up the required biasing conditions in the stage, when no transducer input signal is present, to turn the transistor slightly on.

[0006] Current In flows through the resistor 13 as base current and charging current for the capacitor 14, and also through the collector of transistor 12 as collector current resulting from this base current. Under quiescent conditions, capacitor 14 is charged to a potential which allows an emitter current to flow through resistor 16 equal to I_D, the ratio of collector current to base current being determined by the current gain of the transistor 12. The quiescent value of the collector voltage relative to the reference potential 15 is given by the expression:

$$V_C = I_D \left\{ R_{16} + \frac{R_{13}}{1 + h_{FE}} \right\} + V_{BE}$$

where

 $V_C =$ collector voltage

dark current $I_D =$

 $R_{16} =$ resistance of resistor 16 resistance of resistor 13

 $R_{13} =$ current gain of transistor 12

 $h_{FE} =$

 $V_{BE} =$ base-emitter voltage of transistor 12.

[0007] With the component values shown in Figure 1, and assuming I_D , h_{FE} and V_{BE} to be 1 μA , 40 and 550 mV, respectively, this yields a collector voltage slightly in excess of 0.55 V. In practice, diode 19 will usually be subject to ambient light, which will generate a DC current adding to the dark current In. This, in turn, will increase the collector voltage V_C above its dark-current value; however, provided the current gain h_{FE} of the transistor 12 is high and the value of the emitter resistor 16 is low, collector voltage is dominated by the V_{BF} of the transistor 12 and the circuit will be relatively insensitive to changes in ambient-light level.

[0008] Since the collector voltage under quiescent conditions is so low, a diode 20 may be added as shown to lift the output voltage of the circuit to a level which can more easily be dealt with by subsequent circuitry.

[0009] When now a transmitted pulse of light is detected by the diode 19, a pulse of current is produced in the diode 19. This flows in the first instance through resistor 13, not through the collector of the transistor 12 since the potential on the base of the transistor has not yet had the chance to rise due to the fact that the voltage on the capacitor 14 cannot instantaneously change. This creates a pulse of voltage across resistor 13 and a corresponding positive-going voltage pulse on the collector approximately equal to $I_P \times R_{13}$. This collector pulse has substantially the same pulse width as the transmitted pulse. It is this pulse which is detected and decoded in conventional remote-control systems.

[0010] A disadvantage of known receiver arrangements using the above circuit is that, since the positivegoing pulse appearing on the collector is fast and can also be of large amplitude, any subsequent circuitry used to detect and decode the received pulse has to exhibit a high bandwidth to cope with this. High-bandwidth amplifying and other devices require high supply currents to operate effectively, and where such an arrangement is incorporated in a portable, battery-operated unit, which is often the case, the drain on the battery can be considerable.

[0011] It would be desirable to provide an arrangement which seeks to overcome or mitigate the above

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disadvantages.

[0012] In accordance with a first aspect of the invention, there is provided a receiver arrangement for use in a remote-control system, comprising a receiver stage for receiving a current pulse from a transducer and for outputting a voltage output signal in response to the current pulse, and a pulse detector stage for receiving the voltage outpur signal of the receiver stage and for providing a data output signal in dependence thereon, the receiver stage may comprising an amplifying element having first and second output terminals and an input terminal, the first and second output terminals being connected respectively to a transducer input node and to a first reference potential, the input terminal being connected to the first output terminal through a first resistance and to the first reference potential through a first capacitance, the output of the receiver stage being taken from the transducer input node whereby the voltage output signal comprises a first pulse substantially coincident with the received current pulse and a second, immediately following, opposite-going pulse at the end of the received current pulse having a pulses width greater than that of the first pulse, characterised in that the pulse detector stage is arranged to provide the data output signal in response to the second pulse.

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[0013] By basing the detection of a received current pulse not on a conventionally used fast pulse from the receiver stage, which coincides with the received current pulse output from the transducer, but on a slower and wider pulse following the fast pulse, correspondingly slower, cheaper and lower-current processing devices may be employed in the subsequent pulse detector stage. In addition, the second pulse is easier to detect, as it directly follows a disturbance known to be in the opposite direction. The result is an increased receiver sensitivity.

[0014] The receiver stage may be arranged to limit the amplitude of the second pulse. Such limiting prevents overloading of the receiver stage during high input signal conditions.

[0015] The second output terminal may be connected to the first reference potential through a second resistance, which has the advantage of helping to stabilise the operating conditions of the amplifying element.

[0016] A voltage-shifter may be advantageously interposed between the first output terminal of the amplifying element and the transducer input node. This lifts the quiescent output voltage level of the receiver stage and facilitates the subsequent pulse detection process.

[0017] A transducer may be connected between the transducer input node and a second reference potential.
[0018] The amplifying element is preferably a bipolar transistor

[0019] The detector stage may include a pulse discriminator stage, for forming a first output signal representative of the average level of the output signal of the receiver stage and a second output signal representative of the instantaneous level of the output signal of the

receiver stage, and a comparator stage for comparing the first and second output signals of the pulse detector stage and providing, on the basis of that comparison, the data output signal.

[0020] The pulse discriminator stage may include first and second voltage followers for providing the first and second output signals of the pulse discriminator stage, the first and second voltage-followers being arranged to be commonly supplied with a signal representative of the output signal of the receiver stage, and the first voltage-follower being arranged to provide the first output signal of the pulse discriminator stage through a low-pass filter. The filter preferably includes a third resistance and a second capacitance connected in series between the output of the first voltage follower and a reference potential.

[0021] By arranging for the output of one of the voltage followers to be low-pass filtered, two different signals may be derived from the pulse discriminator stage, the difference of which signals represents the pulse component of the receiver stage output signal. Any quiescent component of that output signal, representing largely the ambient light level experienced by the transducer, is common-mode as far as the voltage followers are concerned.

[0022] A fourth resistance may be connected in parallel with the second capacitance, the fourth resistance serving to adjust the sensitivity of the receiver arrangement.

[0023] A second voltage shifter may be interposed between the receiver stage and the first and second voltage followers of the pulse discriminator stage. The second voltage shifter may include a third voltage follower feeding the first and second voltage followers. At least one diode element may be interposed between the third voltage follower and the first and second voltage followers. The advantage of this is that it complements the voltage-shifting effect of the first voltage shifter associated with the receiver stage.

[0024] A current source may be included in the output circuit of each voltage follower, establishing an output current in each follower. The voltage followers are preferably emitter followers.

[0025] The amplifying element and the first and second voltage followers may be transistors of one polarity type, while the third voltage follower may be a transistor of the opposite polarity type.

[0026] A buffer stage may be interposed between the receiver stage and the pulse detector stage. The buffer stage may be arranged to amplify the output signal of the receiver stage.

[0027] According to a second aspect of the invention, there is provided a remote control apparatus characterised by a receiver arrangement, as described above, and an infrared transducer connected thereto.

[0028] The invention will now be described, by way of example only, with reference to the drawings, of which:

Figure 1 is a circuit diagram of a known infrared receiver front-end stage;

Figure 2 is a graph illustrating the behaviour of the front-end stage shown in Figure 1 when it is exposed to a high-amplitude transducer current pulse; Figure 3 is a graph similar to that of Figure 2, but for a low-amplitude transducer current pulse, and Figure 4 is a schematic diagram of a pulse detector means in a receiver arrangement according to the invention.

[0029] Referring now to Figure 2, when a data pulse is transmitted to a receiver incorporating the circuit shown in Figure 1, the diode 19 in the receiver generates a corresponding current pulse which is shown as current I_P in Figure 2. I_P starts at time t_0 and lasts in this case for 20 μ S. The current pulse, which in this case results from a very strong received signal, has an amplitude of $25 \,\mu\text{A}$ and at the end of the $20 \,\mu\text{S}$ period the current into the receiver stage returns to its quiescent level, the dark current, I_D , which is 1 μ A. At $t=t_0$, the collector voltage V_C rises instantaneously from its quiescent value of approximately 0.55V to 0.55 + $(25 \,\mu\text{A}\times160\,\text{K})\approx4.5\text{V}$, upon which it decreases rapidly as the share of IP flowing through resistor 13 is progressively diverted into the collector of transistor 12 due to the increase of charge on capacitor 14.

[0030] At the end of the 25 μ S current pulse, a discontinuity in the V_C curve occurs as the current entering the receiver stage decreases suddenly from I_D+I_P to I_D . At this point, the transistor stage looks like a common-emitter amplifier stage with emitter degeneration due to resistor 16, in which the input voltage of the stage is the voltage appearing across the capacitor 14 and the gain G of the stage is:

$$G = -\frac{R_{13}}{R_{16} + r_{e}}$$

where

$$r_e = \frac{kT}{q.I_C}$$

and kT/q = 26 mV at room temperature, and $I_C = I_D + I_P =$ 26 μ A. The collector load is the resistor 13 fed from the voltage on the capacitor 14 at the moment the input current pulse ends. The result is a flow of current from the capacitor 14 through resistor 13 to the collector of transistor 12, a negative-going voltage pulse being thereby produced on the collector. The magnitude of this pulse can be approximated by the equation:

$$V_P = \frac{0.7.I_P.T}{C_{14}} \cdot \frac{R_{13}}{\frac{26\,mV}{I_D + I_P} + R_{16}}$$

[0031] The pulse decays as the capacitor 14 slowly discharges through resistor 13 (see the part of the V_C curve marked "X" and the corresponding part of the curve of capacitor voltage (V14) in Figure 2). This causes some stretching of the pulse which can facilitate detection of the pulse in a subsequent pulse detection stage. At high levels of diode pulse current the transistor will saturate, giving a maximum pulse amplitude of slightly under 0.6 V and considerable stretching of the pulse. At lower levels of diode current, the negative-going pulse will not send the transistor 12 into saturation and stretching will be more limited (see Figure 3, where $I_P = 1 \mu A$). [0032] Because the voltage across the capacitor 14 takes time to reach its maximum level in response to a constant-current input $(I_D + I_P)$, which is the equivalent behaviour, in terms of current, of an inductor being fed from a constant-voltage input, and because the voltage on the collector goes sharply negative when the input current pulse is removed and decays back to its quiescent value, which is equivalent to the "back-emf" behaviour of an inductor when a driving voltage is removed from it, this circuit has sometimes been called a "gyratorconfigured" stage.

[0033] It is this negative-going "back-emf-type" pulse which is now used by the receiver arrangement according to the invention as the basis of further processing in the pulse detection means shown in Figure 4.

[0034] In Figure 4 an amplifier/buffer 30 receives the output voltage signal from the receiver stage shown in Figure 1 and amplifies an AC component of that output signal by a set amount, while subjecting a DC component, corresponding mainly to the ambient light level of the diode 19's environment, to unity-gain amplification only. This minimises the effects of ambient radiation on the pulse detection circuitry, while boosting the desired pulse signal component of the receiver stage output.

[0035] The output of the amplifier/buffer 30 is taken to a pulse detector stage 40, consisting of an emitter follower stage 41, two parallel-driven emitter follower stages 42, 43 and associated current sources 44, 45, 46 and a low-pass filter 47. Emitter follower 41 comprises a PNP transistor 48, a voltage shifter 49, consisting of three series-connected diodes, and the current source 44. The base of transistor 48 is fed from the output of the amplifier/buffer 30, while the collector of the transistor 48 is taken to a reference potential 15 and the emitter is taken to a positive supply rail 51 by way of the voltage shifter 49 and the current source 44. The voltage shifter lifts the low quiescent input voltage present on the base of the transistor 48 to a level more suitable for following circuitry.

[0036] The junction of the voltage shifter 49 and the current source 44 is taken to the commoned bases of

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NPN transistors 52 and 53, which, together with current sources 45 and 46, respectively, form the emitter followers 42 and 43. The collectors of transistors 52, 53 are taken to the positive supply rail 51, while the emitters of these transistors are taken to their respective current sources 45, 46, in the case of follower 42 via a resistor 54. Resistor 54 forms one half of the low-pass filter 47, the other half being constituted by the parallel combination of a capacitor 55 and a resistor 56. Resistor 56 and capacitor 55 are connected across the current source 45.

[0037] In operation, the quiescent output of the amplifier/buffer 30 is effectively shifted in potential to the potential existing on the emitters of transistors 52 and 53. A potential difference is set up between points "A" and "B" in Figure 4 due to the current flowing through the resistor 54 and the range-setting resistor 56. Where the receiver arrangement according to the invention is to be used at the maximum end of its range, i.e. where the diode current pulse is small, resistor 56 may be omitted or else made very high impedance, e.g. 3 $\mbox{M}\Omega.$

[0038] Under quiescent conditions, there will be a fixed potential difference between points "A" and "B", virtually regardless of the quiescent voltage level at the output of the receiver stage. Although this potential difference will be to some extent dependent on the quiescent voltage level present on the emitter of transistor 42, due to a non-constant current flowing through resistors 54 and *56*, this effect is minimised by the relative insensitivity of the receiver stage to ambient light levels, as already mentioned.

[0039] The signals on the points "A" and "B" of the pulse detector stage 40 are taken to the inputs of a comparator stage 60 based around a comparator 61. Under no-signal conditions, input 62 of comparator 61 is at a higher voltage than input 63 and consequently the data output 64 of the comparator 61 is held low.

[0040] When a diode pulse signal from the receiver stage is received on the input of the amplifier 30, the emitter follower 43 provides on its emitter a faithful reproduction of that signal, i.e. the voltage V_C shown in Figure 2, whereas the emitter follower 42 provides at the junction of the resistor 54 and the current source 45 the average of that signal. This is due to the action of the filter comprised principally of the resistor 54 and the capacitor 55. The collector voltage V_C responds to the incident, transmitted data pulse by going high for a time duration corresponding to the duration of the received pulse. This same positive-going pulse is reproduced at point "B", but not at point "A" due to the filtering action of the filter 47. Thus, the already existing potential difference between points "A" and "B" is increased and the output 64 of the comparator 61 continues to be held low. [0041] At the end of the initially received current pulse, however, V_C drops suddenly and goes negative (see Figure 2). Depending on the value chosen for the resistor 56, the negative excursion of V_C will be sufficient to change the output state of the comparator 61 and a

data output pulse will be sent out to a following decoder stage (not shown).

[0042] It can be seen that the voltage on point "A" under signal conditions is required to be substantially invariant, and this in turn requires the time constant of the filter 47 to be suitably long compared with the decay time of the negative-going pulse (see curve "X" in Figure 2). [0043] This circuit may be realised in discrete or integrated form. It should be appreciated that, where the circuit is committed to silicon integration, the individual elements of the receiver arrangement shown in Figures 1 and 4 will represent only the basic essential elements necessary for the working of a specific embodiment of the invention, and in practice it may be necessary to introduce additional elements not shown in the diagrams or mentioned in the description in the course of the integration process.

20 Claims

- A receiver arrangement for use in a remote-control system, comprising a receiver stage for receiving a current pulse from a transducer (19) and for outputing a voltage output signal in response to the current pulse, and a pulse detector stage (40) for receiving the voltage output signal of the receiver stage and for providing a data output signal (64) in dependence thereon, the receiver stage comprising an amplifying element (12) having first and second output terminals and an input terminal, the first and second output terminals being connected respectively to a transducer input node and to a first reference potential (15), the input terminal being connected to the first output terminal through a first resistance (13) and to the first reference potential (15) through a first capacitance (14), the output of the receiver stage being taken from the transducer input node whereby the voltage output signal comprises a first pulse substantially coincident with the received current pulse and a second, immediately following, opposite-going pulse at the end of the received current pulse having a pulse width greater than that of the first pulse, characterised in that the pulse detector stage (40) is arranged to provide the data output signal in response to the second pulse.
- A receiver arrangement as claimed in claim 1, characterised in that the receiver stage is arranged to limit the amplitude of the second pulse.
- A receiver arrangement as claimed in claim 1 or 2, characterised in that the second output terminal is connected to the first reference potential (15) through a second resistance (16).
- A receiver arrangement as claimed in any one of the preceding claims, characterised by a first volt-

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age-shifter (20) interposed between the first output terminal of the amplifying element (12) and the transducer input node.

- 5. A receiver arrangement as claimed in any one of the preceding claims, **characterised by** a transducer (190 connected between the transducer input node and a second reference potential (18).
- **6.** A receiver arrangement as claimed in any one of the preceding claims. **characterised in that** the amplifying element is a bipolar transistor (12).
- 7. A receiver arrangement as claimed in an one of the preceding claims, characterised in that the pulse detector stage (40) comprises a pulse discriminator stage (42, 43) for forming a first output signal (A) representative of the average level of the output signal of the receiver stage and a second output signal (B) representative of the instantaneous level of the output signal of the receiver stage, and a comparator stage (60) for comparing the first and second output signals of the pulse detector stage and providing, one the basis of that comparison, the data output signal.
- 8. A receiver arrangement as claimed in claim 7, characterised in that the pulse discriminator (42, 43) stage comprises first and second voltage followers (52, 53) for providing the first and second output signals (A, B) of the pulse discriminator stage (42, 43) the first and second voltage-followers (52, 53) being arranged to be commonly supplied with a signal representative of the output signal of the receiver stage, and the first voltage-follower (52) being arranged to provide the first output signal (A) of the pulse discriminator stage (42,43) through a low-pass filter (47).
- 9. A receiver arranged as claimed in claim 8, characterised in that the low-pass filter (47) comprises a third resistance (54) and a second capacitance (55) connected in series between the output of the first voltage follower (52) and a reference potential (15).
- 10. A receiver arrangement as claimed in claim 9, characterised by a fourth resistance (56) connected in parallel with the second capacitance (55), the fourth resistance (56) serving to adjust the sensitivity of the receiver arrangement.
- 11. A receiver arrangement as claimed in any one of claims 8 to 10, **characterised by** a second voltage shifter (41) interposed between the receiver stage and the first and second voltage followers (52, 53) of the pulse discriminator stage (42, 43).
- 12. A receiver arrangement as claimed in claim 11,

characterised in that the second voltage shifter (41) comprises a third voltage follower (48) feeding the first and second voltage followers (52, 53).

- 13. A receiver arrangement as claimed in claim 12, characterised by at least one diode element (49) interposed between the third voltage follower (48) and the first and second voltage followers (52, 53).
- 10 14. A receiver arrangement as claimed in any one of claims 8 to 13, characterised by a current source (44-46) in the output circuit of each voltage follower (48, 52, 53).
- 5 15. A receiver arrangement as claimed in any one of claims 8 to 14, characterised in that the voltage followers (48, 52, 53) are emitter followers.
 - 16. A receiver arrangement as claimed in claim 6, claim 12, and claim 15, **characterised in that** the amplifying element (12) and the first and second voltage followers (52, 53) are transistors of one polarity type, while the third voltage follower (48) is a transistor of the opposite polarity type.
 - 17. A remote-control apparatus characterised by a receiver arrangement as claimed in any one of the preceding claims and an infrared transducer connected thereto.

Patentansprüche

Empfängeranordnung zur Verwendung in einem Fernsteuerungssystem mit einer Empfängerstufe zum Empfangen eines Stromimpulses von einem Wandler (19) und zum Ausgeben eines Spannungsausgangssignals als Antwort auf den Stromimpuls, und einer Impulsdetektorstufe (40) zum Empfangen des Spannungsausgangssignals der Empfängerstufe und zum Liefern eines Datenausgangssignals (64) in Abhängigkeit davon, wobei die Empfängerstufe ein Verstärkungselement (12) mit einem ersten und einem zweiten Ausgangsanschluß und einem Eingangsanschluß aufweist, der erste und der zweite Ausgangsanschluß mit einem Eingangsknoten des Wandlers bzw. mit einem ersten Referenzpotential (15) verbunden sind, der Eingangsanschluß mit dem ersten Ausgangsanschluß über einen ersten Widerstand (13) und mit dem ersten Referenzpotential (15) über eine erste Kapazität (14) verbunden ist, das Ausgangssignal der Empfängerstufe vom Eingangsknoten des Wandlers abgenommen wird, wodurch das Spannungsausgangssignal einen ersten Impuls, der im wesentlichen mit dem empfangenen Stromimpuls übereinstimmt, und einen zweiten, unmittelbar folgenden, entgegengesetzten Impuls am Ende des

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empfangenen Stromimpulses aufweist, der eine Impulsbreite hat, die größer ist als die des ersten Impulses, **dadurch gekennzeichnet**, **daß** die Impulsdetektorstufe (40) so eingerichtet ist, daß sie das Datenausgangssignal als Antwort auf den zweiten Impuls liefert.

- Empfängeranordnung nach Anspruch 1, dadurch gekennzeichnet, daß die Empfängerstufe so eingerichtet ist, daß die Amplitude des zweiten Impulses begrenzt wird.
- Empfängeranordnung nach Anspruch 1 oder 2, dadurch gekennzeichnet, daß der zweite Ausgangsanschluß mit dem ersten Referenzpotential (15) über einen zweiten Widerstand (16) verbunden ist.
- 4. Empfängeranordnung nach einem der vorhergehenden Ansprüche, gekennzeichnet durch einen ersten Spannungsangleicher (20), der zwischen den ersten Ausgangsanschluß des Verstärkungselements (12) und den Eingangsknoten des Wandlers geschaltet ist.
- 5. Empfängeranordnung nach einem der vorhergehenden Ansprüche, gekennzeichnet durch einen Wandler (19), der zwischen den Eingangsknoten des Wandlers und ein zweites Referenzpotential (18) geschaltet ist.
- 6. Empfängeranordnung nach einem der vorhergehenden Ansprüche, dadurch gekennzeichnet, daß das Verstärkungselement ein bipolarer Transistor (12) ist.
- 7. Empfängeranordnung nach einem der vorhergehenden Ansprüche, dadurch gekennzeichnet, daß die Impulsdetektorstufe (40) aufweist: eine Impulsdiskriminatorstufe (42, 43) zur Bildung eines ersten Ausgangssignals (A), das den durchschnittlichen Pegel des Ausgangssignals der Empfängerstufe darstellt, und eines zweiten Ausgangssignals (B), das den Momentanpegel des Ausgangssignals der Empfängerstufe darstellt, und eine Komparatorstufe (60) zum Vergleichen des ersten und zweiten Ausgangssignals der Impulsdetektorstufe und Liefern des Datenausgangssignals auf der Grundlage dieses Vergleichs.
- 8. Empfängeranordnung nach Anspruch 7, dadurch gekennzeichnet, daß die Impulsdiskriminatorstufe (42, 43) einen ersten und einen zweiten Spannungsfolger (52, 53) zum Liefern des ersten und zweiten Ausgangssignals (A, B) der Impulsdiskriminatorstufe (42, 43) aufweist, wobei der erste und zweite Spannungsfolger (52, 53) so eingerichtet sind, daß sie gemeinsam mit einem Signal versorgt werden, das das Ausgangssignal der Empfänger-

stufe darstellt, und der erste Spannungsfolger (52) so eingerichtet ist, daß er das erste Ausgangssignal (A) der Impulsdiskriminatorstufe (42, 43) über ein Tiefpaßfilter (47) liefert.

- Empfängeranordnung nach Anspruch 8, dadurch gekennzeichnet, daß das Tiefpaßfilter (47) einen dritten Widerstand (54) und eine zweite Kapazität (55) aufweist, die zwischen den Ausgang des ersten Spannungsfolgers (52) und ein Referenzpotential (15) in Reihe geschaltet sind.
- 10. Empfängeranordnung nach Anspruch 9, gekennzeichnet durch einen vierten Widerstand (56), der mit der zweiten Kapazität (55) parallelgeschaltet ist, wobei der vierte Widerstand (56) dazu dient, die Empfindlichkeit der Empfängeranordnung einzustellen.
- 20 11. Empfängeranordnung nach einem der Ansprüche 8 bis 10, gekennzeichnet durch einen zweiten Spannungsangleicher (41), der zwischen die Empfängerstufe und den ersten und zweiten Spannungsfolger (52, 53) der Impulsdiskriminatorstufe (42, 43) geschaltet ist.
 - **12.** Empfängeranordnung nach Anspruch 11, **dadurch gekennzeichnet, daß** der zweite Spannungsangleicher (41) einen dritten Spannungsfolger (48) aufweist, die den ersten und zweiten Spannungsfolger (52, 53) versorgt.
 - **13.** Empfängeranordnung nach Anspruch 12, **gekennzeichnet durch** mindestens ein Diodenelement (49), das zwischen den dritten Spannungsfolger (48) und den ersten und zweiten Spannungsfolger (52, 53) geschaltet ist.
- 14. Empfängeranordnung nach einem der Ansprüche
 8 bis 13, gekennzeichnet durch eine Stromquelle (44-46) in der Ausgangsschaltung jedes Spannungsfolgers (48, 52, 53).
 - 15. Empfängeranordnung nach einem der Ansprüche 8 bis 14, dadurch gekennzeichnet, daß die Spannungsfolger (48, 52, 53) Emitterfolger sind.
 - 16. Empfängeranordnung nach Anspruch 6, 12 und 15, dadurch gekennzeichnet, daß das Verstärkungselement (12) und der erste und zweite Spannungsfolger (52, 53) Transistoren einer Polaritätsart sind, wogegen der dritte Spannungsfolger (48) ein Transistor der entgegengesetzten Polaritätsart ist.
 - 17. Fernsteuerungsvorrichtung, gekennzeichnet durch eine Empfängeranordnung nach einem der vorhergehenden Ansprüche und einen mit dieser verbundenen Infrarotwandler.

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Revendications

- 1. Une structure de récepteur pour l'utilisation dans un système de télécommande, comprenant un étage récepteur pour recevoir une impulsion de courant provenant d'un transducteur (19) et pour émettre un signal de sortie de tension en réponse à l'impulsion de courant, et un étage détecteur d'impulsions (40) pour recevoir le signal de sortie de tension de l'étage récepteur et pour fournir sous la dépendance de celui-ci un signal de sortie de données (64), l'étage récepteur comprenant un élément d'amplification (12) ayant des première et seconde bornes de sortie et une borne d'entrée, les première et seconde bornes de sortie étant respectivement connectées à un noeud d'entrée de transducteur et à un premier potentiel de référence (15), la borne d'entrée étant connectée à la première borne de sortie par l'intermédiaire d'une première résistance (13) et au premier potentiel de référence (15) par l'intermédiaire d'une première capacité (14), le signal de sortie de l'étage récepteur étant prélevé sur le noeud d'entrée de transducteur, grâce à quoi le signal de sortie de tension comprend une première impulsion qui coïncide pratiquement avec l'impulsion de courant reçue, et une seconde impulsion de sens opposé, qui suit immédiatement, à la fin de l'impulsion de courant reçue, ayant une largeur d'impulsion supérieure à celle de la première impulsion, caractérisée en ce que l'étage détecteur d'impulsions (40) est conçu pour fournir le signal de sortie de données en réponse à la seconde impulsion.
- Une structure de récepteur selon la revendication 1, caractérisée en ce que l'étage récepteur est conçu pour limiter l'amplitude de la seconde impulsion.
- Une structure de récepteur selon la revendication 1 ou 2, caractérisée en ce que la seconde borne de sortie est connectée au premier potentiel de référence (15) par l'intermédiaire d'une seconde résistance (16).
- 4. Une structure de récepteur selon l'une quelconque des revendications précédentes, caractérisée par un premier élément de décalage de tension (20) interposé entre la première borne de sortie de l'élément d'amplification (12) et le noeud d'entrée de transducteur.
- 5. Une structure de récepteur selon l'une quelconque des revendications précédentes, caractérisée par un transducteur (19) connecté entre le noeud d'entrée de transducteur et un second potentiel de référence (18).
- 6. Une structure de récepteur selon l'une quelconque

des revendications précédentes, caractérisée en ce que l'élément d'amplification est un transistor bipolaire (12).

- 7. Une structure de récepteur selon l'une quelconque des revendications précédentes, caractérisée en ce que l'étage détecteur d'impulsions (40) comprend un étage discriminateur d'impulsions (42, 43) pour former un premier signal de sortie (A) représentatif du niveau moyen du signal de sortie de l'étage récepteur, et un second signal de sortie (B) représentatif du niveau instantané du signal de sortie de l'étage récepteur, et un étage comparateur (60) pour comparer les premier et second signaux de sortie de l'étage détecteur d'impulsions et pour fournir le signal de sortie de données, sur la base de cette comparaison.
- 8. Une structure de récepteur selon la revendication 7, caractérisée en ce que l'étage discriminateur d'impulsions (42, 43) comprend des premier et second suiveurs de tension (52, 53) pour fournir les premier et second signaux de sortie (A, B) de l'étage discriminateur d'impulsions (42, 43), les premier et second suiveurs de tension (52, 53) étant adaptés pour recevoir de façon commune un signal représentatif du signal de sortie de l'étage récepteur, et le premier suiveur de tension (52) étant adapté pour fournir le premier signal de sortie (A) de l'étage discriminateur d'impulsions (42, 43) par l'intermédiaire d'un filtre passe-bas (47).
- 9. Une structure de récepteur selon la revendication 8, caractérisée en ce que le filtre passe-bas (47) comprend une troisième résistance (54) et une seconde capacité (55) connectées en série entre la sortie du premier suiveur de tension (52) et un potentiel de référence (15).
- 40 10. Une structure de récepteur selon la revendication 9, caractérisée par une quatrième résistance (56) connectée en parallèle avec la seconde capacité (55), la quatrième résistance (56) ayant pour fonction de régler la sensibilité de la structure de récepteur.
 - 11. Une structure de récepteur selon l'une quelconque des revendications 8 à 10, caractérisée par un second élément de décalage de tension (41) interposé entre l'étage récepteur et les premier et second suiveurs de tension (52, 53) de l'étage discriminateur d'impulsions (42, 43).
 - 12. Une structure de récepteur selon la revendication 11, caractérisée en ce que le second élément de décalage de tension (41) comprend un troisième suiveur de tension (48) alimentant les premier et second suiveurs de tension (52, 53).

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- 13. Une structure de récepteur selon la revendication 12, caractérisée par au moins une diode (49) interposée entre le troisième suiveur de tension (48) et les premier et second suiveurs de tension (52, 53).
- **14.** Une structure de récepteur selon l'une quelconque des revendications 8 à 13, **caractérisée par** une source de courant (44-46) dans le circuit de sortie de chaque suiveur de tension (48, 52, 53).
- 15. Une structure de récepteur selon l'une quelconque des revendications 8 à 14, caractérisée en ce que les suiveurs de tension (48, 52, 53) sont des circuits à charge d'émetteur (émetteurs-suiveurs).
- 16. Une structure de récepteur selon la revendication 6, la revendication 12 et la revendication 15, caractérisée en ce que l'élément d'amplification (12) et les premier et second suiveurs de tension (52, 53) sont des transistors d'un type de polarité, tandis que le troisième suiveur de tension (48) est un transistor du type de polarité opposé.
- 17. Un appareil de télécommande caractérisé par une structure de récepteur selon l'une quelconque des revendications précédentes et un transducteur infrarouge connecté à celle-ci.

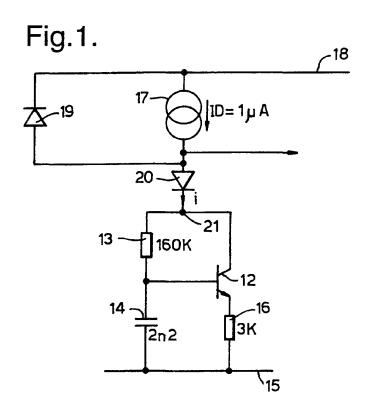
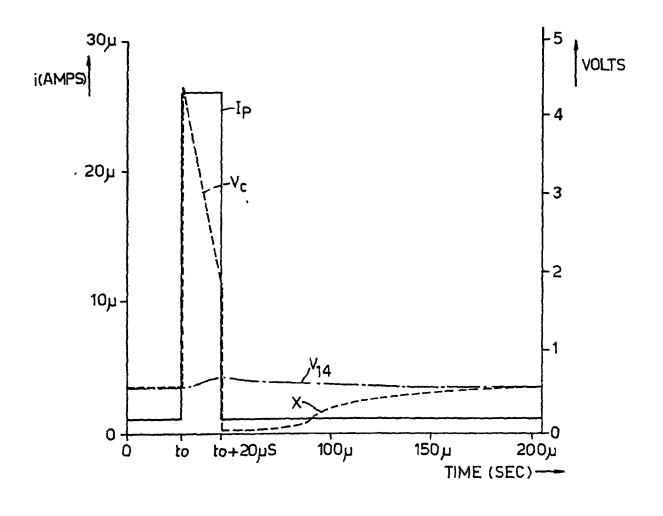
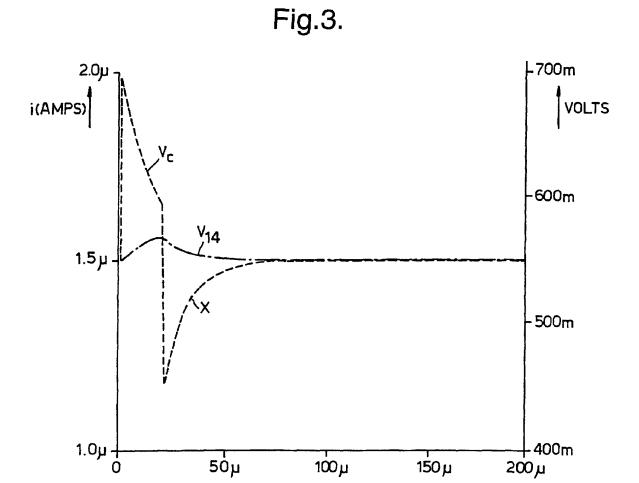


Fig.4. <u>40</u> 51 Aus| <u>5</u>2 53 `42 <u>60</u> <u>30</u> 40K_B -49 54 DATA TO DECODER 763 61 64 45 - 56 2µA 55

Fig.2.





TIME (SEC) -